

HD74UH08

2-input AND Gate

REJ03D0202-0500Z (Previous ADE-205-017C (Z)) Rev.5.00 Feb.02.2004

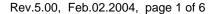
Description

The HD74UH08 is high speed CMOS two input AND gate using silicon gate CMOS process. With CMOS low power dissipation, it provides high-speed equivalent to LS-TTL series. The internal circuit of three stages construction with buffer provides wide noise margin and stable output.

Features

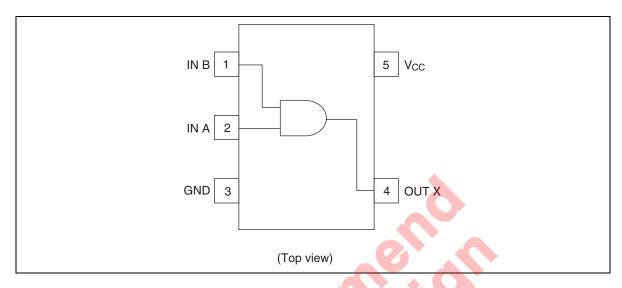
- Encapsulated in very small 5pins package of $2.9 \times 1.6 \times 1.1$ mm, the efficiency to mount on substrate is significantly improved.
- The basic gate function is lined up as Renesas uni logic series.
- Supplied on emboss taping for high-speed automatic mounting.
- Electrical characteristics equivalent to the HD74HC08 Supply voltage range: 2 to 6 V
 Operating temperature range: -40 to +85°C
- $|I_{OH}| = I_{OL} = 2 \text{ mA (min)}$
- Ordering Information

Part Name	Package Type	Package Code	Package Abbreviation	Taping Abbreviation (Quantity)	
HD74UH08EL	MPAK-5 pin	MPAK-5V	_	EL (3,000 pcs/reel)	

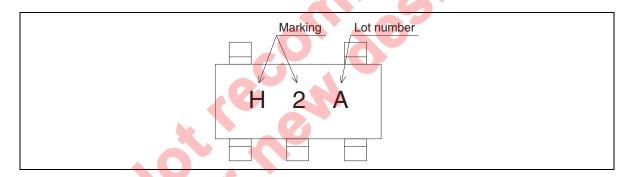




Pin Arrangement



Article Indication



Absolute Maximum Ratings

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	-0.5 to +7.0	V	
Input voltage	V _{IN}	-0.5 to V _{CC} +0.5	V	
Output voltage	V _{OUT}	-0.5 to V _{CC} +0.5	V	
Input diode current	I _{IK}	±20	mA	
Output diode current	I _{OK}	±20	mA	
Output current	I _{OUT}	±25	mA	
V _{CC} /GND current	I _{CC} , I _{GND}	±25	mA	
Power dissipation	P _T	200	mW	
Storage temperature	Tstg	-65 to +150	°C	

HD74UH08

Recommended Operating Conditions

Item	Symbol	Ratings	Unit	
Supply voltage	V _{CC}	2 to 6	V	
Input voltage	V _{IN}	0 to V _{CC}	V	
Output voltage	V _{OUT}	0 to V _{CC}	V	
Operating temperature	Topr	-40 to +85	°C	
Input rise/fall time	t _r , t _f	0 to 1000 (V _{CC} = 2.0 V)	ns	
		0 to 500 (V _{CC} = 4.5 V)		
		0 to 400 (V _{CC} = 6.0 V)		

Electrical Characteristics

		\mathbf{V}_{cc}	Ta =	25°C		Ta = −40 to 85°C				
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Condition	าร
Input voltage	V _{IH}	2.0	1.5	_	_	1.5		V		
		4.5	3.15	_	_	3.15	_	6		
		6.0	4.2	_		4.2	4-0			
	V _{IL}	2.0	_	_	0.5	-	0.5	V		
		4.5	_	<u> </u>	1.35	_	1.35	_		
		6.0	_	0	1.8	-1	1.8	_		
Output voltage	V _{OH}	2.0	1.9	2.0	_	1.9	_	V	$V_{IN} = V_{IH}$	$I_{OH} = -20 \ \mu A$
		4.5	4.4	4.5	40	4.4	_	_		
		6.0	5.9	6.0	-7	5.9	_	_		
		4.5	4.18	4.31		4.13	_	_		$I_{OH} = -2 \text{ mA}$
		6.0	5.68	5.80	_	5.63	_	_		$I_{OH} = -2.6 \text{ mA}$
	VoL	2.0	(E)	0.0	0.1	_	0.1	V	$V_{\text{IN}} = V_{\text{IH}} \text{ or } V_{\text{IL}}$	I _{OL} = 20 μA
		4.5	_	0.0	0.1	_	0.1	_		
		6.0	_	0.0	0.1	_	0.1	_		
		4.5	_	0.17	0.26	_	0.33	_		I _{OL} = 2 mA
		6.0	_	0.18	0.26	_	0.33	_		I _{OL} = 2.6 mA
Input current	I _{IN}	6.0	_	_	±0.1	_	±1.0	μΑ	$V_{IN} = V_{CC}$ or GI	ND
Operating current	Icc	6.0	_	_	1.0	_	10.0	_	$V_{IN} = V_{CC}$ or GN	ND

Switching Characteristics

$$(C_L = 15 \text{ pF}, t_r = t_f = 6 \text{ ns}, V_{CC} = 5 \text{ V})$$

 $Ta = 25^{\circ}C$

Item	Symbol	Min Typ		Max	Unit	Test Conditions	
Output rise/fall time	t _{TLH} t _{THL}	_	5	10	ns	See Test circuit	
Propagation delay time	t _{PLH} t _{PHL}	_	7	15	ns	See Test circuit	

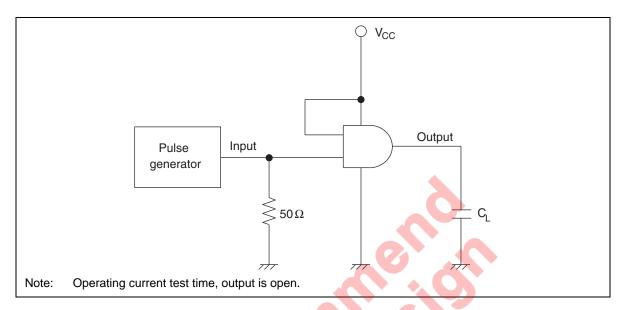
$$(C_L = 50 \text{ pF}, t_r = t_f = 6 \text{ ns})$$

		\mathbf{V}_{CC}	Ta = 1	25°C		Ta =	-40 to 85°C		
Item	Symbol	(V)	Min	Тур	Max	Min	Max	Unit	Test Conditions
Output rise/fall time	t _{TLH}	2.0	_	50	125	7	155	ns	See Test circuit
	t _{THL}	4.5	_	14	25	7	31	7	
		6.0		12	21	_	26	_	
Propagation delay time	t _{PLH}	2.0	_	48	100	<u>~ (</u>	125	ns	See Test circuit
	t _{PHL}	4.5	_	12	20	7	25	_	
		6.0	+ C	9	17	7	21	_	
Input capacitance	C _{IN}	- (5	10	_	10	pF	
Equivalent capacitance	C _{PD}	4		10	7	_	_	_	

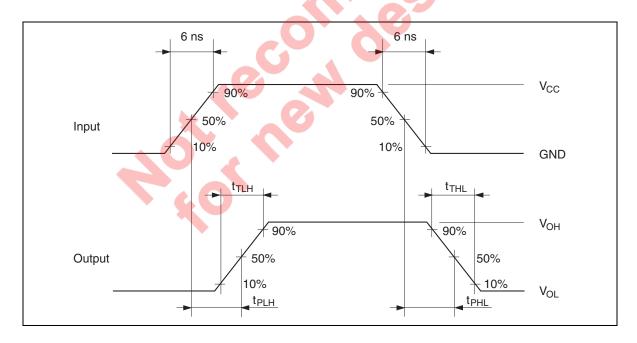
Note: C_{PD} is equivalent capacitance inside of the IC calculated from the operating current without load (see test circuit). The average operating current without load is calculated according to the expression below.

$$I_{CC(opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$$

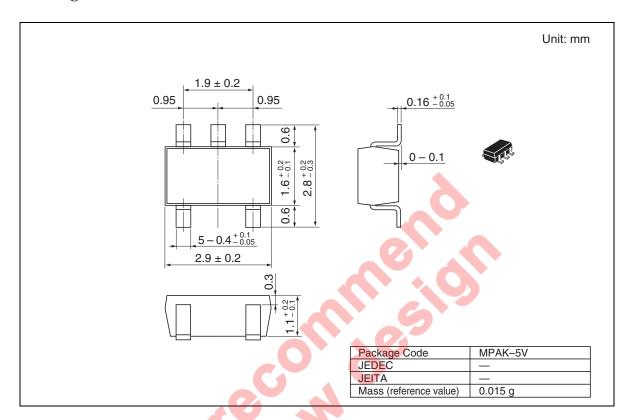
Test Circuit



Waveforms



Package Dimensions



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